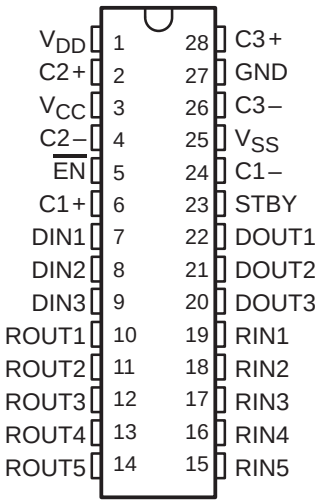
- **Single-Chip and Single-Supply Interface for IBM PC/AT Serial Port**
- **Meets or Exceeds the Requirements of EIA/TIA-232-E and ITU v.11 Standards**
- **Operates With 3.3-V or 5-V Supplies**
- **One Receiver Remains Active During Standby (Wake-Up Mode)**
- **Designed to Operate at 128 kbits Over a 3-m Cable**
- **Low Standby Current . . . 5 μA Max**
- **ESD Protection on RS-232 Pins Meets or Exceeds 4 kV (HBM) and 1.5 kV (HBM) on All Pins Per MIL-STD-883C, Method 3015**
- **External Capacitors . . . 0.1 μF**
  (V_{CC} = 3.3 V Five External Capacitors)
  (V_{CC} = 5 V Four External Capacitors)
- **Packaged in Shrink Small-Outline Package With 25-Mil Terminal Pitch and Maximum 2-mm Height (SSOP)**
- **Accepts 5-V Logic Input With 3.3-V Supply**
- **Pin Compatible With the SN75LV4735**
- **Applications**
  EIA/TIA-232 Interface
  Battery-Powered Systems, PDAs
  Notebook, Laptop, and Palmtop PCs
  External Modems and Hand-Held Terminals

DB PACKAGE†
(TOP VIEW)



† The DB package is only available in left-ended tape and reel (order part number SN75LV4737ADBLE).

description

The SN75LV4737A‡ consists of three line drivers, five line receivers, and a charge-pump circuit. It provides the electrical interface between an asynchronous communication controller and the serial-port connector and meets the requirements of EIA/TIA-232-E. This combination of drivers and receivers matches those needed for the typical serial port used in an IBM PC/AT or compatibles. The charge pump and five small external capacitors allow operation from a single 3.3-V supply and four capacitors for operation from a 5-V supply.

The device has flexible control options for power management when the serial port is inactive. A common disable for all of the drivers and receivers is provided with the active-high STBY input. The active-low $\overline{EN}$ input is an enable for one receiver to implement a wake-up feature for the serial port. All the logic inputs can accept signals from controllers operating from a 5-V supply even though the SN75LV4737A is operating from 3.3 V.

The SN75LV4737A is characterized for operation over the temperature range of 0°C to 70°C.

‡ Patent-pending design

Function Tables

EACH DRIVER

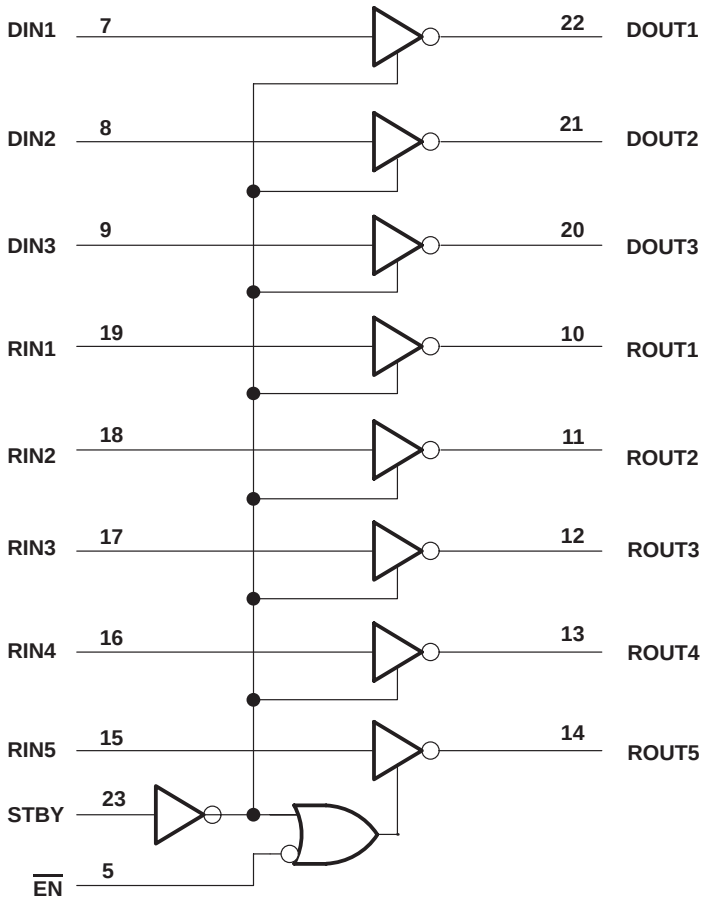
INPUTS		OUTPUTS
DIN	STBY	DOUT
X	H	Z
L	L	H
H	L	L
Open	L	L

EACH RECEIVER

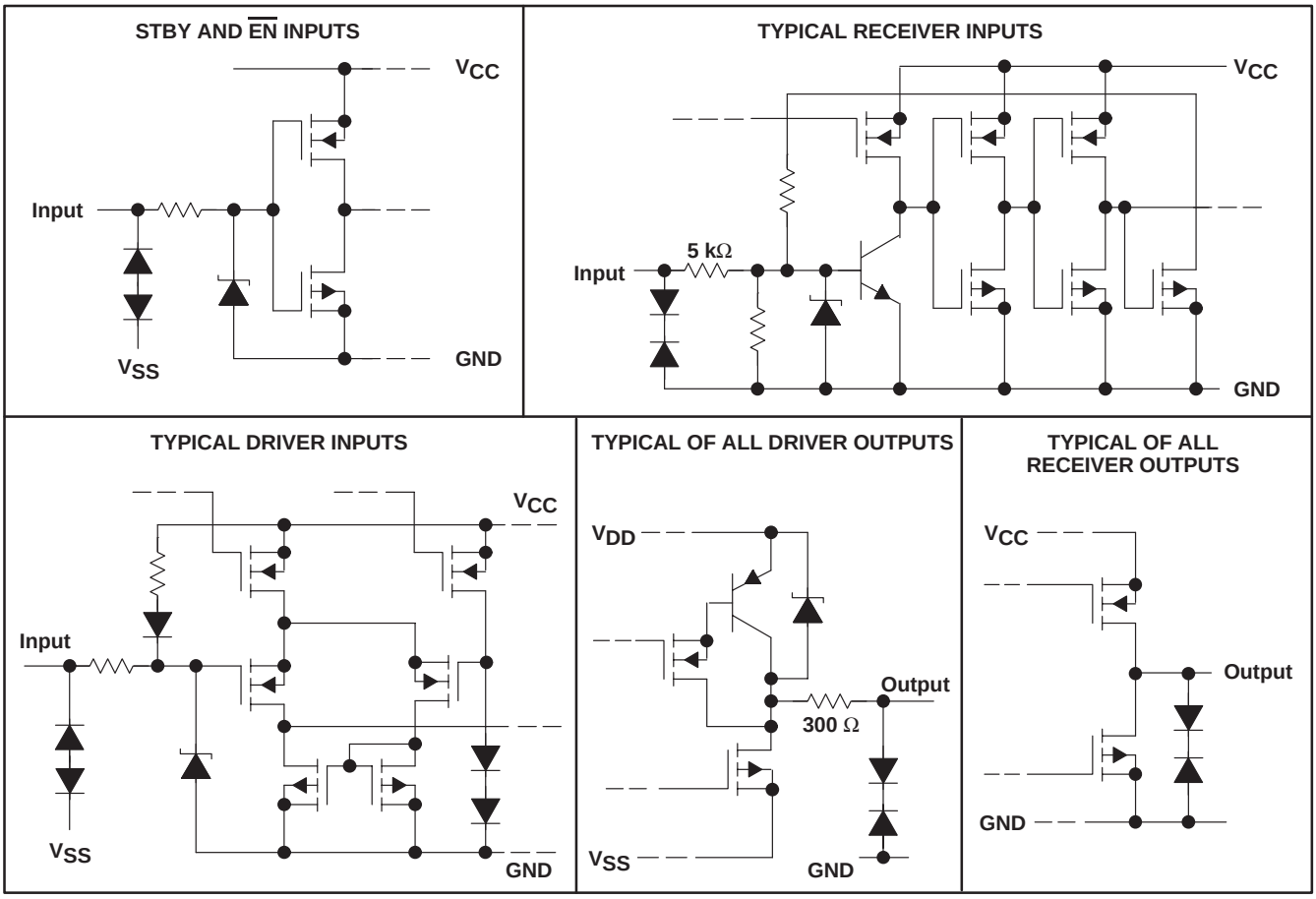
INPUTS				OUTPUTS	
STBY	$\overline{EN}$	RIN5	RIN1 – RIN4	ROUT5	ROUT1 – ROUT4
H	H	X	X	Z	Z
H	L	H	X	L	Z
H	L	L	X	H	Z
L	X	L	L	H	H
L	X	H	H	L	L

H = high level, Low = low level, X = irrelevant, Z = high impedance (off)

logic diagram (positive logic)



schematics of inputs and outputs



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{CC}	7 V
Positive output supply voltage, V_{DD} (see Note 1)	15 V
Negative output supply voltage, V_{SS}	–15 V
Input voltage range, V_I: Driver	–3 V to 7 V
Receiver	–30 V to 30 V
Output voltage range, V_O: Driver	V_{SS} – 0.3 V to V_{DD} + 0.3 V
Receiver	–0.3 V to 7 V
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T_A	0°C to 70°C
Storage temperature range, T_{stg}	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltages are with respect to network GND.

DISSIPATION RATING TABLE

PACKAGE	$T_A \le 25°C$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25°C$	$T_A = 70°C$ POWER RATING
DB	668 mW	5.3 mW/°C	430 mW

recommended operating conditions

			MIN	NOM	MAX	UNIT
Supply voltage	V_{CC} = 3.3 V		3	3.3	3.6	V
	V_{CC} = 5 V		4.5	5	5.5	V
Driver high-level input voltage, V_{IH}	V_{CC} = 3.3 V	DIN, $\overline{EN}$, STBY	2			V
	V_{CC} = 5 V	DIN	2			
		$\overline{EN}$, STBY	2.5			
Driver low-level input voltage, V_{IL}	DIN, $\overline{EN}$, STBY				0.8	V
Receiver input voltage, V_I					±30	V
External capacitor	3.3-V operation (C1, C2, C3, C4, C5), 5-V operation (C1, C3, C4, C5), See Note 2 and Figures 6 and 7		0.1			µF
Operating free-air temperature, T_A			0		70	°C

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figures 6 and 7)

PARAMETER		TEST CONDITIONS		V_{CC} = 3.3 V			V_{CC} = 5 V			UNIT
				MIN	TYP†	MAX	MIN	TYP†	MAX	
V_{DD}	Positive supply voltage	No load		8	10		7	8.7		V
V_{SS}	Negative supply voltage	No load			−9.5	−7		−8	−6	V
I_I	Input current ($\overline{EN}$, STBY)	See Notes 3 and 4				±2			±2	µA
I_{CC}	Supply current	No load, Inputs open	STBY at GND, $\overline{EN}$ at V_{CC} or GND	8.4	10	18	10	12	20.7	mA
	Supply current (standby mode) (see Note 3)		$\overline{EN}$, STBY at V_{CC}			5			5	µA
	Supply current (wake-up mode) (see Note 4)		$\overline{EN}$ at GND, STBY at V_{CC}			10			10	µA

† All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V and T_A = 25°C.

NOTES: 2. C2 is only needed for 3.3-V operation.
3. When STBY mode is not used, STBY input must be taken low.
4. When wake-up mode is not used, $\overline{EN}$ input must be taken high.

DRIVER SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
V_{OH}	High-level output voltage	R_L = 3 kΩ		5.5	7		V
V_{OL}	Low-level output voltage	R_L = 3 kΩ			−6	−5	V
I_{IH}	High-level input current	$V_I = V_{CC}$				1	μA
I_{IL}	Low-level input current	V_I at GND				−10	μA
I_{OS}	Short-circuit output current (see Note 5)	V_{CC} = 3.6 V,	V_O = 0 V		±15	±40	mA
		V_{CC} = 5.5 V,	V_O = 0 V				
r_o	Output resistance	$V_{CC} = V_{DD} = V_{SS}$ = 0 V,	V_O = ±2 V	300	500		Ω

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
t_{PLH}	Propagation delay time, low- to high-level output	C_L = 50 pF, R_L = 3 kΩ to 7 kΩ, See Figure 1	V_{CC} = 3.3 V	100	500	850	ns
			V_{CC} = 5 V	100	500	850	ns
t_{PHL}	Propagation delay time, high- to low-level output		V_{CC} = 3.3 V	100	500	850	ns
			V_{CC} = 5 V	100	500	850	ns
t_{PZH}	Output enable time to high level	C_L = 50 pF, See Figure 2	R_L = 3 kΩ to 7 kΩ,		1	5	ms
t_{PZL}	Output enable time to low level				3	7	ms
t_{PHZ}	Output disable time from high level	C_L = 50 pF, R_L = 3 kΩ to 7 kΩ, See Figure 2	V_{CC} = 3.3 V		0.9	3	μs
			V_{CC} = 5 V		0.6	3	
t_{PLZ}	Output disable time from low level		V_{CC} = 3.3 V		0.5	3	
			V_{CC} = 5 V		0.3	3	
SR	Slew rate	C_L = 50 pF, See Figure 1	R_L = 3 kΩ to 7 kΩ,	4		30	V/μs
SR(tr)	Slew rate, transition region	C_L = 2500 pF, See Figure 3	R_L = 3 kΩ to 7 kΩ,	3		30	V/μs

† All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V and T_A = 25°C.

NOTE 5: Short-circuit durations should be controlled to prohibit exceeding the device absolute power dissipation ratings and not more than one output should be shorted at a time.

RECEIVER SECTION

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

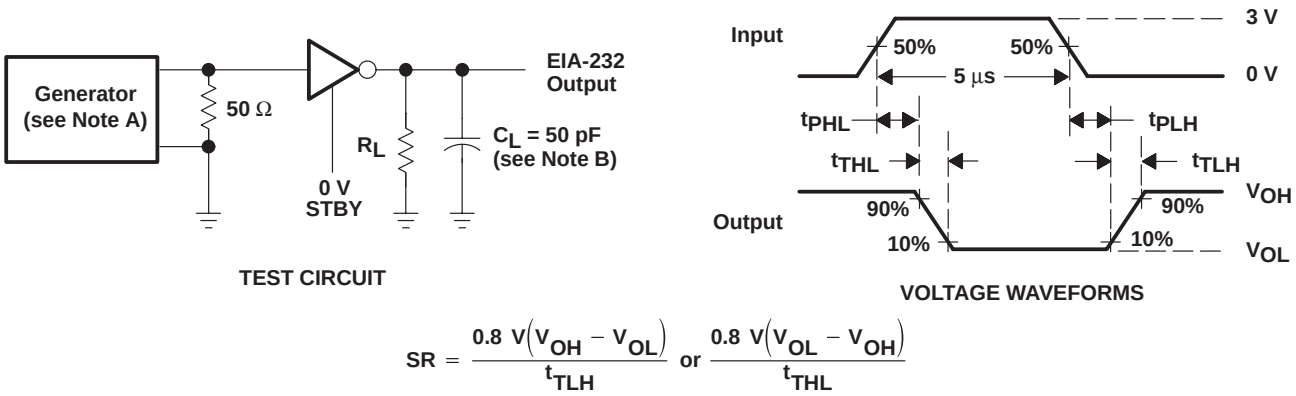
PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
V_{OH}	High-level output voltage	I_{OH} = –2 mA	3.3 V	2.4	3		V
			5 V	3.5	5		V
V_{OL}	Low-level output voltage	I_{OL} = 2 mA			0.2	0.4	V
V_{IT+}	Positive-going input threshold voltage				2.2	2.6	V
$V_{IT–}$	Negative-going input threshold voltage			0.6	1		V
V_{hys}	Input hysteresis ($V_{IT+} – V_{IT–}$)			0.5	1.2	1.8	V
r_i	Input resistance	V_I = ±3 V to ±25 V		3	5	7	kΩ

† All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V and T_A = 25°C.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature, C_L = 50 pF, R_L = 3 kΩ to GND

PARAMETER		TEST CONDITIONS	V_{CC} = 3.3 V			V_{CC} = 5 V			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
t_{PLH}	Propagation delay time, low- to high-level output	See Figure 4	10	70	200	10	70	200	ns
t_{PHL}	Propagation delay time, high- to low-level output		10	60	200	10	55	200	ns
t_{PLH}	Propagation delay time, low- to high-level output (wake-up mode)			40	200		40	200	µs
t_{PHL}	Propagation delay time, high- to low-level output (wake-up mode)			90	500		70	500	ns
t_{PZH}	Output enable time to high level	See Figure 5		3	10		1.2	10	µs
t_{PZL}	Output enable time to low level			100	250		60	250	ns
t_{PHZ}	Output disable time from high level		100	200	600	100	150	600	ns
t_{PLZ}	Output disable time from low level			130	250		60	250	ns

PARAMETER MEASUREMENT INFORMATION



$$SR = \frac{0.8\ V\left(V_{OH} - V_{OL}\right)}{t_{TLH}} \text{ or } \frac{0.8\ V\left(V_{OL} - V_{OH}\right)}{t_{THL}}$$

Figure 1. Driver Propagation Delay Times and Slew Rate (5-μs input)

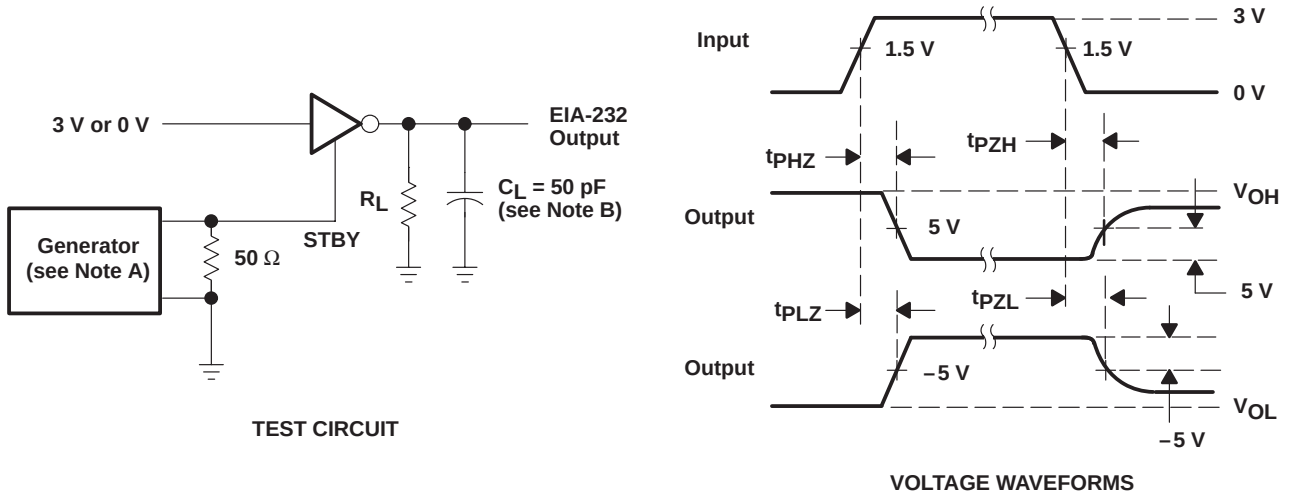
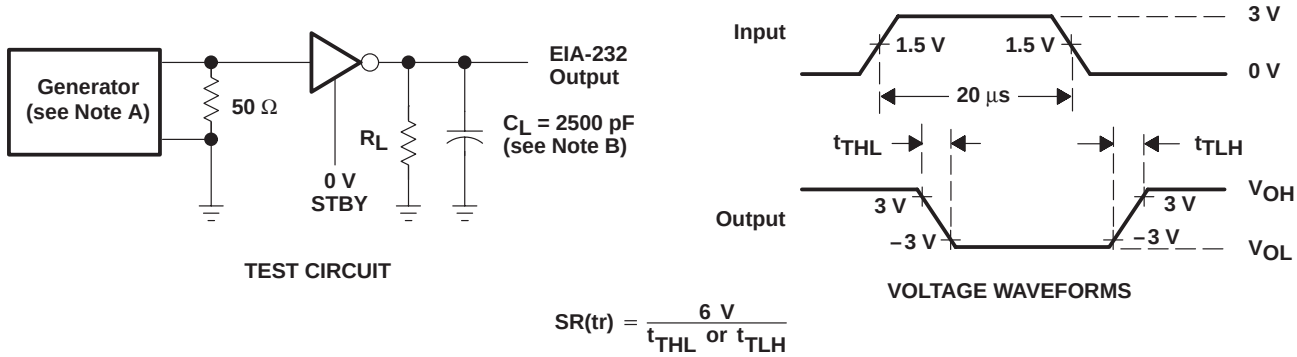


Figure 2. Driver Enable and Disable Test Times



$$SR(tr) = \frac{6\ V}{t_{THL} \text{ or } t_{TLH}}$$

Figure 3. Driver Transition Times and Slew Rate (20-μs input)

NOTES: A. The pulse generator has the following characteristics: Z_O = 50 Ω, 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.
B. C_L includes probe and jig capacitance.

PARAMETER MEASUREMENT INFORMATION

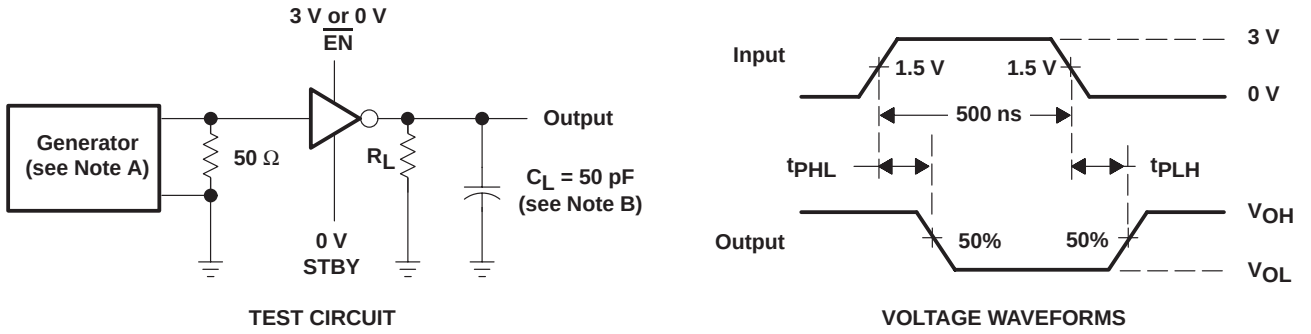


Figure 4. Receiver Propagation Delay Times

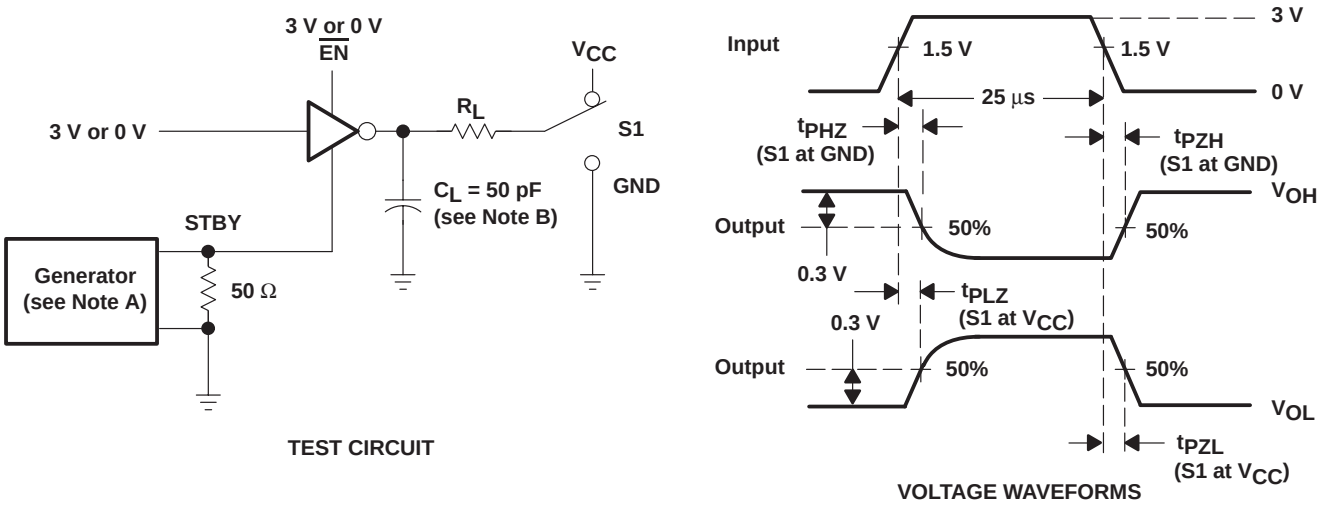
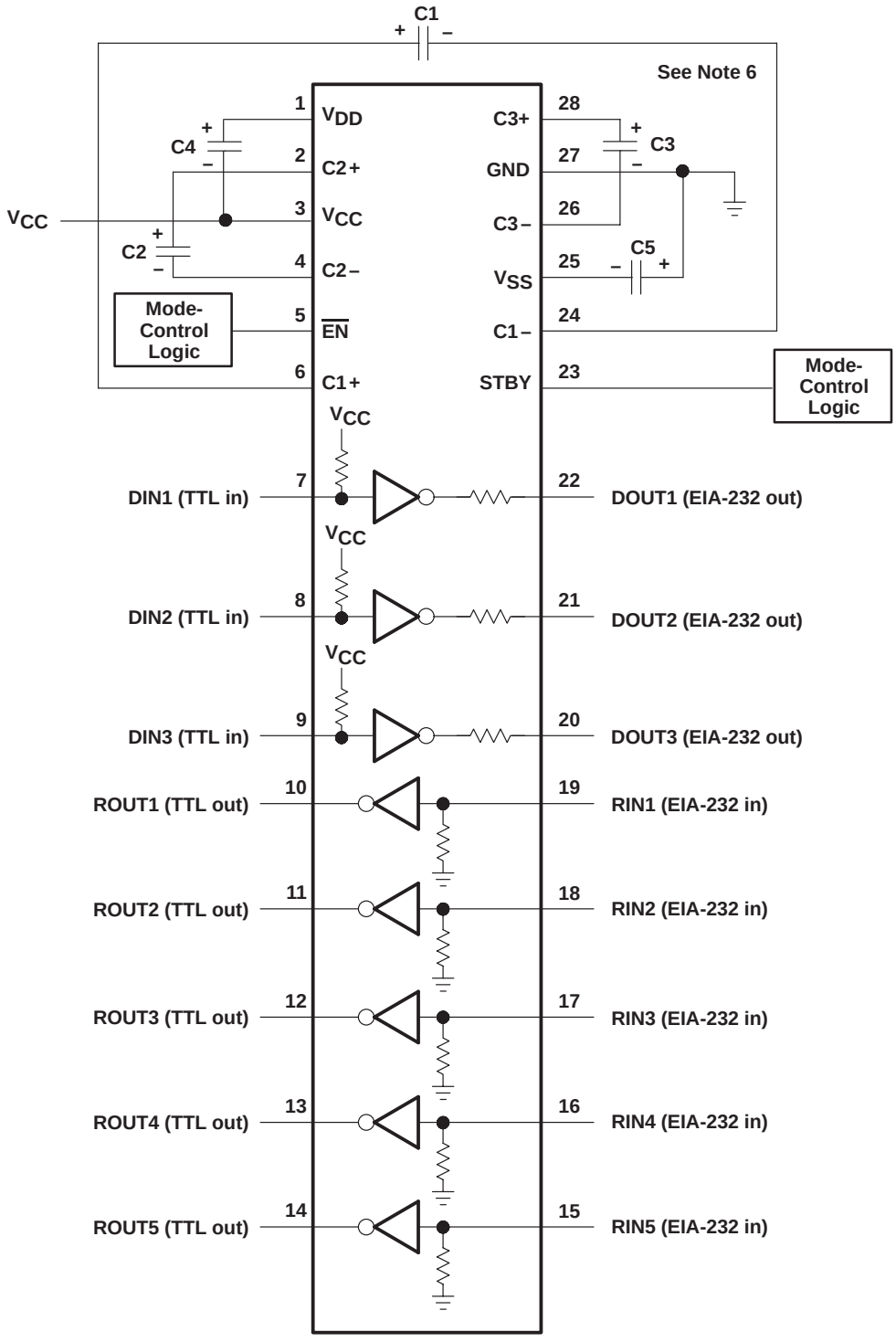


Figure 5. Receiver Enable and Disable Times

NOTES: A. The pulse generator has the following characteristics: PRR = 1 MHz, Z_O = 50 Ω, 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.
B. C_L includes probe and jig capacitance.

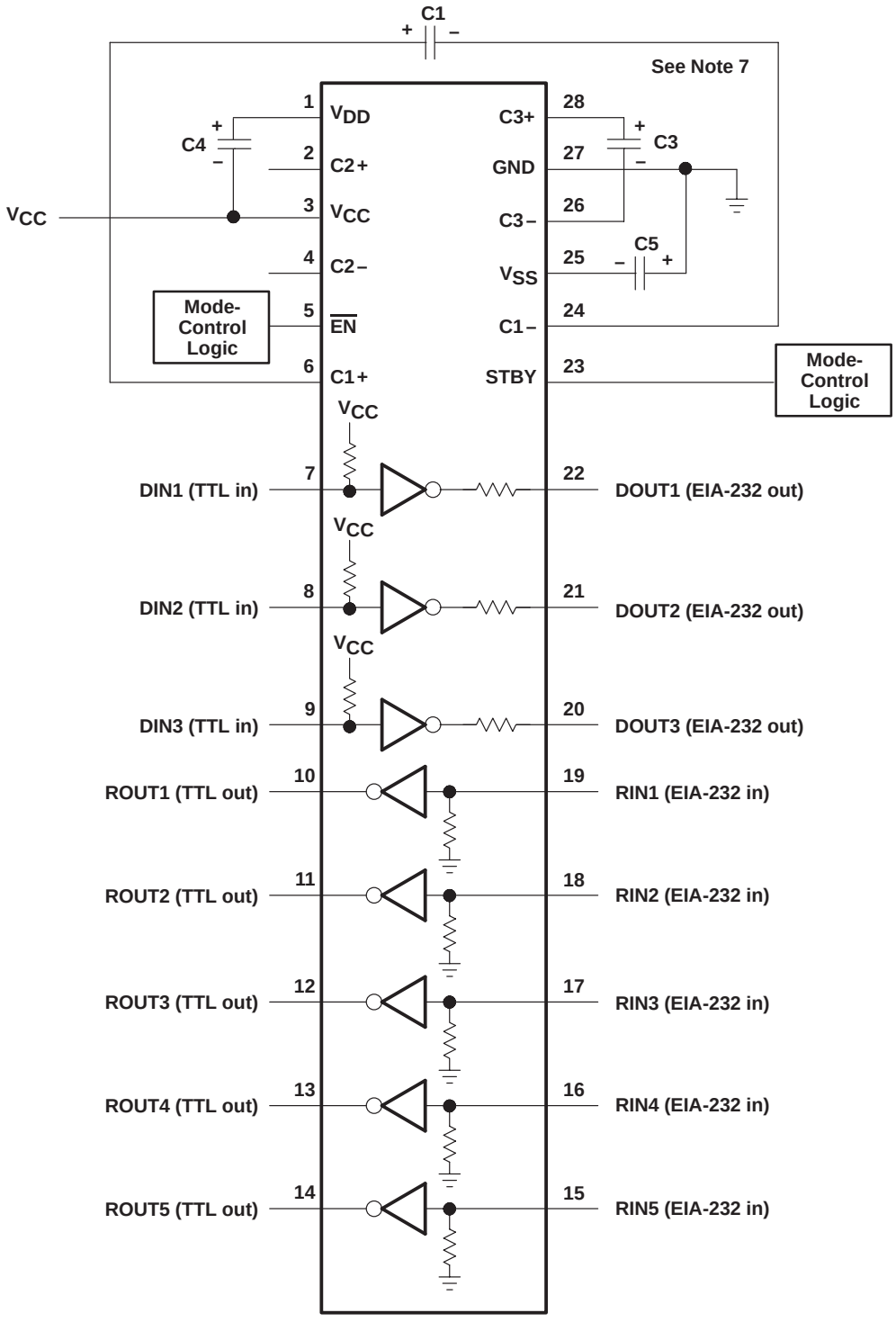
APPLICATION INFORMATION



NOTE 6: C1 = C2 = C3 = C4 = C5 = 0.1 μF

Figure 6. Typical 3.3-V Operating Circuit

APPLICATION INFORMATION



NOTE 7: C2 is not used.
C1 = C3 = C4 = C5 = 0.1 µF

Figure 7. Typical 5-V Operating Circuit

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